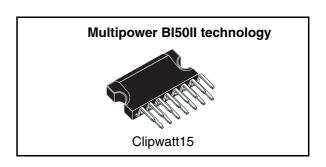


11 W + 11 W amplifier with DC volume control

Features

- 11 W + 11 W output power with $R_L = 8 \Omega$, THD = 10%, $V_{CC} = 28 V$
- Stand-by and mute functions
- Low turn-on and turn-off "pop" noise
- Linear volume control DC coupled to power operational amplifier
- No boucherot cell
- No RC input network for stand-by
- Single supply up to 35 V
- Short-circuit protection
- Thermal overload protection
- Internally fixed gain
- Soft clipping
- Variable output after volume control circuit
- Clipwatt15 package, RoHS



Description

The TDA7495SA is a stereo 11 W + 11 W class AB power amplifier specially designed for high-quality sound and TV applications. Its features include linear volume control, stand-by and mute functions. The TDA7495SA is delivered in the Clipwatt15 package

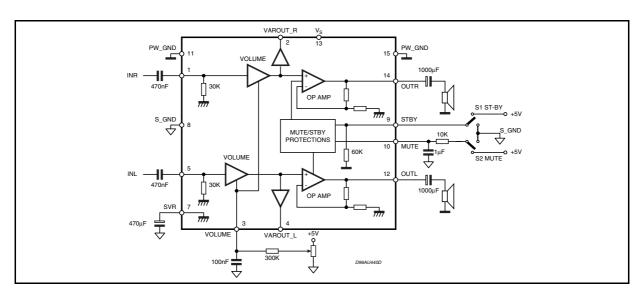


Table 1. Device summary

Order code	Package	Packaging
TDA7495SA	Clipwatt15	Tube

Pin connections TDA7495SA

1 Pin connections

Figure 1. Pin connection (top view)

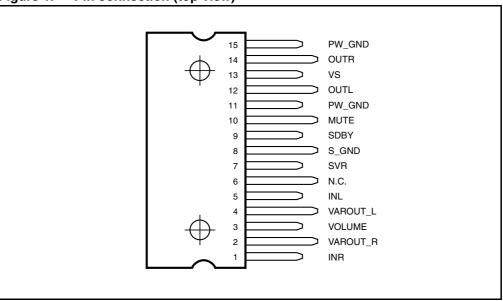


Table 2. Pin description

Number	Name	Description	
1	INR	Input, right channel	
2	VAROUT_R	Volume control output, right channel	
3	VOLUME	Adjust volume	
4	VAROUT_L	Volume control output, left channel	
5	INL	Input, left channel	
6	N.C.	Not connected	
7	SVR	Internal half supply bias	
8	S_GND	Signal ground	
9	STBY	Stand-by (active high)	
10	MUTE	Mute (active high)	
11	PW_GND	Power ground	
12	OUTL	Output, left channel	
13	VS	Power supply	
14	OUTR	Output, right channel	
15	PW_GND	Power ground	

2 Electrical specifications

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _S	DC supply voltage	35	٧
V _{IN}	Maximum input voltage	8	Vpp
P _{tot}	Total power dissipation (T _{amb} = 70° C)	15	W
T _{amb}	Ambient operating temperature	0 to 70	°C
T_{stg} , T_{J}	Storage and junction temperature	-40 to 150	°C
V ₃	Volume control DC voltage	7	V

Table 4. Thermal data

Symbol	Parameter		Тур	Max	Unit
R _{th j-case}	Thermal resistance junction-case		4.5	5.0	°C/W
R _{th j-amb}	Thermal resistance junction-ambient		48		°C/W

Unless otherwise stated, the test conditions for the specifications given in *Table 5* below are: VS = 20 V, $R_L = 8 \Omega$, generator resistance $Rg = 50 \Omega$, $T_{amb} = 25^{\circ} C$. Refer also to the application circuit of *Figure 2 on page 5*.

Table 5. Electrical characteristics

Symbol	Parameter	Test condition	Min	Тур	Max	Unit
V _s	Supply voltage range		11		35	٧
Iq	Total quiescent current			70	100	mA
DCV _{os}	Output DC offset referred to SVR potential	No input signal	-650		650	mV
V _O	Quiescent output voltage			10		٧
		THD = 10%, V _S = 28 V THD = 1%, V _S = 28 V	9.5 7.5	11 8		w
P _O	Output power	THD = 10%, V_S = 20 V, R_L = 4 Ω THD = 1%, V_S = 20 V, R_L = 4 Ω	7 5	8 6		W
		THD = 10%, V _S = 18 V THD = 1%, V _S = 18 V	3.5 2.2	3.8 2.9		W
THD	Total harmonic distortion	$G_{v} = 30 \text{ dB}, P_{O} = 1 \text{ W}, f = 1 \text{ kHz}$			0.4	%
I _{peak}	Peak output current	(internally limited)	1.7	2.4		Α
V _{IN}	Input signal				2.8	V RMS
Ri	Input resistance		22.5	30		kΩ
R _{VarOut}	Output resistance at pins VAROUT_L, VAROUT_R			30	100	Ω

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Table 5. Electrical characteristics (continued)

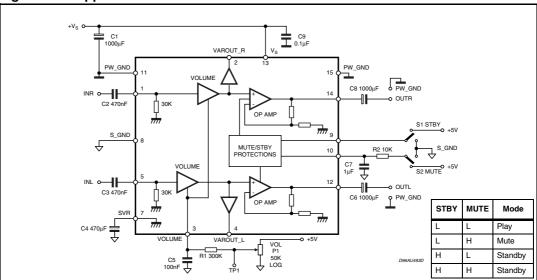
Symbol	Parameter	Test condition	Min	Тур	Max	Unit
R _{L_VarOut}	Load resistance which can be connected to pins VAROUT_L, VAROUT_R		2			kΩ
G _v	Closed-loop gain	VOLUME >4.5 V	28.5	30	31.5	dB
G _{vline}	Volume control output at max gain	VOLUME > 4.5 V, R _{L_VarOut} > 30 k Ω	-1.5	0	1.5	dB
A _{Min_VOL}	Attenuation at minimum volume setting	VOLUME < 0.5 V	80			dB
BW				0.6		MHz
		f = 20 Hz to 22 kHz PLAY, max volume		500	800	μV
e _N	Total output noise	f = 20 Hz to 22 kHz PLAY, max attenuation		100	250	μV
		f = 20 Hz to 22 kHz MUTE		60	150	μV
SR	Slew rate		5	8		V/µs
SVR		f = 1 kHz; max volume C_{SVR} = 470 μ F; V_{RIP} = 1 V RMS	35	39		dB
SVN	Supply voltage rejection	f = 1 kHz; max attenuation C_{SVR} = 470 μF; V_{RIP} = 1 V RMS	55	65		dB
TM	Thermal muting			150		°C
TS	Thermal shut-down			160		°C
Mute, sta	nd-by and input selection	functions				
V _{STBY}	Stand-by threshold		2.3	2.5	2.7	٧
V _{MUTE}	Mute threshold		2.3	2.5	2.7	٧
I _{qSTBY}	Quiescent current in stand-by			0.6	1	mA
A _{MUTE}	Mute attenuation		50	65		dB
I _{STBYbias}	Bias current for pin STBY	In stand-by mode, V _{STBY} = 5 V, V _{MUTE} = 5 V		80		μΑ
		In play or mute mode	-20	-5		μΑ
l==- :	Bias current for pin MUTE	In mute mode		1	5	μΑ
I _{MUTEbias}	Dias current for pill MOTE	In play mode		0.2	2	μΑ

TDA7495SA Applications

3 Applications

3.1 Circuit diagram and components

Figure 2. Application circuit



The recommended values of the external components are those shown on the application circuit of *Figure 2*. *Table 6* below indicates how the performance changes when component values different to the recommended are used.

Table 6. Application suggestions

Symbol	Suggested value	Purpose	Larger than suggestion	Smaller than suggestion
R1	300 kΩ	Volume control circuit	Larger volume regulation time	Smaller volume regulation time
R2	10 kΩ	Mute time constant	Larger mute on/off time	Smaller mute on/off time
P1	50 kΩ	Volume control		
C1	1000 μF	Supply voltage decoupling		Danger of oscillation
C2, C3	470 nF	Input AC coupling	Lower low-frequency cutoff	Higher low-frequency cutoff
C4	470 μF	Ripple rejection	Better SVR	Worse SVR
C5	100 nF	Volume control time constant	Larger volume regulation time	Smaller volume regulation time
C6, C8	1000 μF	Output AC coupling	Lower low-frequency cutoff	Higher low-frequency cutoff
C7	1 μF	Mute time constant	Larger mute on/off time	Smaller mute on/off time
C9	100 nF	Supply voltage decoupling		Danger of oscillation

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Applications TDA7495SA

3.2 Board layout

Figure 3. PCB and component layout

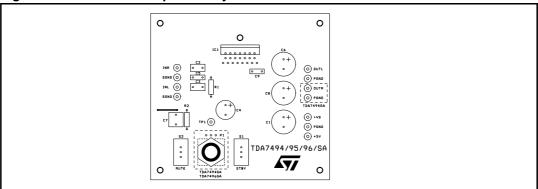


Figure 4. Evaluation board bottom layer layout

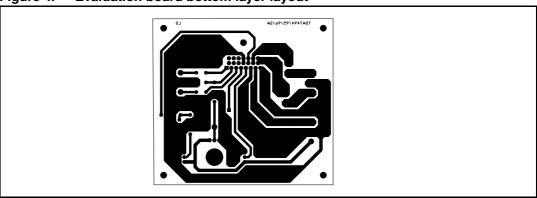
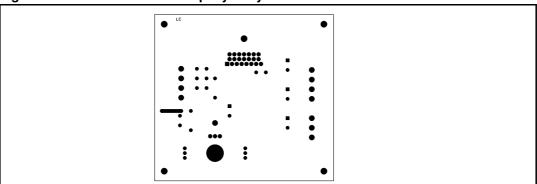


Figure 5. Evaluation board top layer layout



TDA7495SA Applications

3.3 Power-up/down sequence

In order to reduce the loud speaker "pop" noise when switching the device on or off we recommend that you follow the sequence of operations shown in *Figure 6* below.

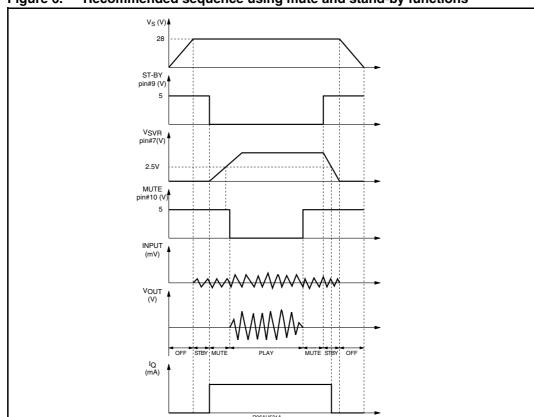


Figure 6. Recommended sequence using mute and stand-by functions

Using the mute function only

To simplify the application, pin STBY can be connected directly to ground so that the device is always active. Then, to maintain the power-up/down performance you should adhere to the following conditions:

- At turn-on the transition mute to play must be made when pin SVR is higher than 2.5 V.
- At turn-off the TDA7495SA must be set to mute from the play condition before pin SVR falls below 2.5 V.

Applications TDA7495SA

3.4 Typical electrical characteristics

Unless otherwise stated, the test conditions for the electrical characteristics given in the figures below are: VS = 20 V, R_L = 8 Ω , f = 1 kHz, generator resistance R_g = 50 Ω , T_{amb} = 25° C. Refer also to the application circuit of *Figure 2 on page 5*.

Figure 7. Output power vs supply voltage

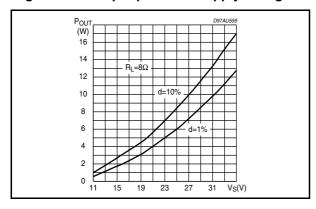


Figure 8. Distortion vs output power

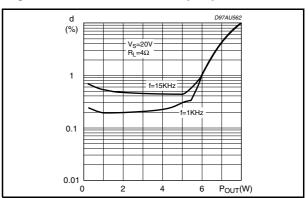


Figure 9. Distortion vs output power

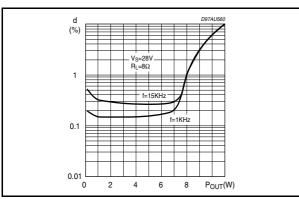


Figure 10. Stand-by attenuation vs Vpin#9

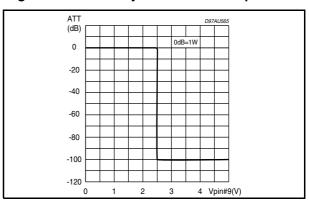
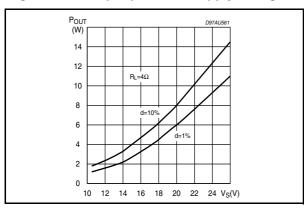
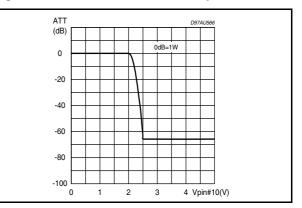


Figure 11. Output power vs supply voltage



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Figure 12. Mute attenuation vs Vpin#10



TDA7495SA Applications

Figure 13. Supply voltage vs frequency

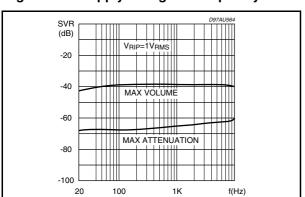


Figure 14. Gain vs volume control voltage (#3)

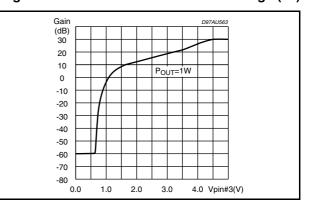
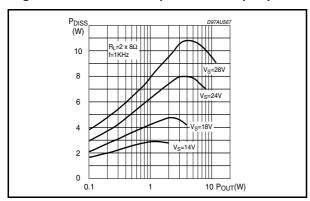
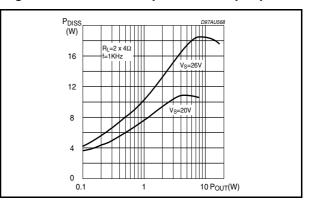


Figure 15. Power dissipation vs output power Figure 16. Power dissipation vs output power





3.5 Internal equivalent circuits

Figure 17. Pin: SVR

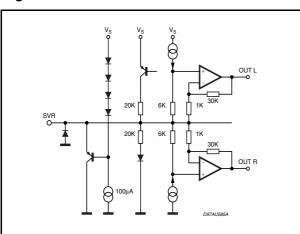
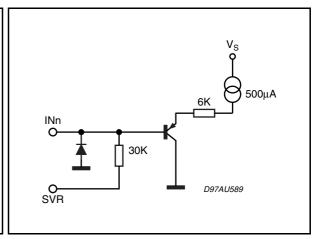


Figure 18. Pins: INL, INR



Applications TDA7495SA

Figure 19. Pins: PW-GND, S-GND

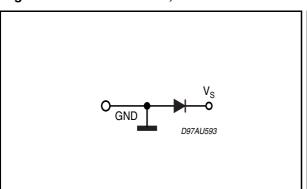


Figure 20. Pin: STBY

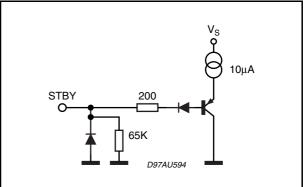


Figure 21. Pin: MUTE

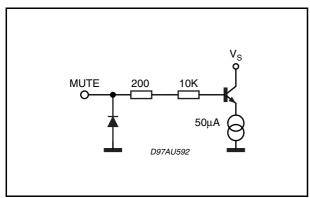


Figure 22. Pins: OUTR, OUTL

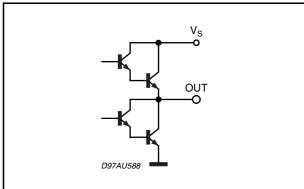


Figure 23. Pins: VAROUT_L, VAROUT_R

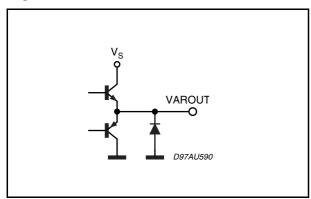
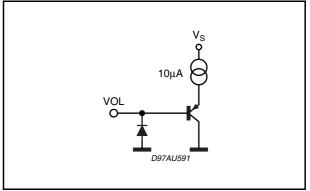


Figure 24. Pin: VOLUME



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TDA7495SA Thermal considerations

4 Thermal considerations

In order to avoid the intervention of the thermal protection, it is important to choose an adequate heatsink.

The parameters that influence the heatsink size are:

- maximum dissipated power for the device (P_{dmax})
- maximum thermal resistance junction to case (R_{Th i-c})
- maximum ambient temperature T_{amb max}

Example:

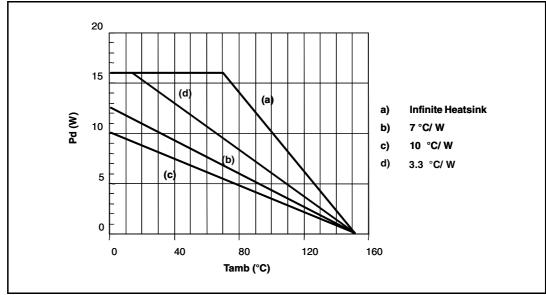
For
$$V_{CC}$$
 = 20 V, R_L = 8 Ω , $R_{Th\ j\text{-}c}$ = 5° C/W, T_{amb_max} = 50° C
$$P_{dmax} = Number_of_channels * \frac{V_{cc}^2}{2\Pi^2 \cdot R_L} = 5 \text{ W}$$

For the heatsink,

$$R_{Th j-c} = \frac{150 - T_{amb_max}}{P_{d max}} - R_{Th j-c} = \frac{100}{5} - 5 = 15^{\circ}C/W$$

Figure 25 shows the power derating curve for the device.

Figure 25. Power derating curve



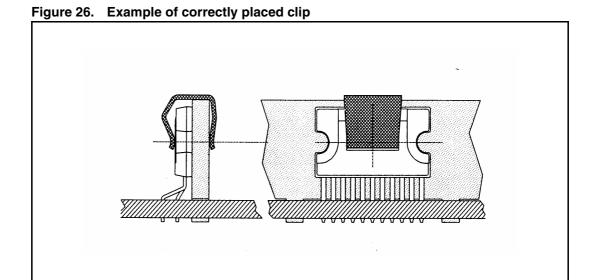
5 Clipwatt mounting suggestions

The suggested method for securing the Clipwatt package on an external heat sink is by a spring clip placed as close as possible to the center of the plastic body, as indicated in the example of *Figure 26*.

Thermal grease can be used to further reduce the thermal resistance of the contact between package and heatsink.

The clip should apply a force of 7 - 10 kg to provide sufficient pressure for a good contact. Care must be taken to ensure that the contact pressure on the package does not exceed 15 kg/mm².

As an example, if the clip applies a 15-kg force on the package then the clip must have a contact area of at least 1 mm².

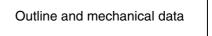


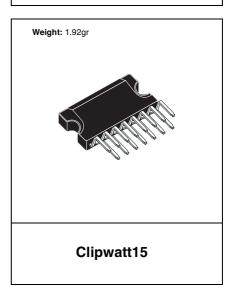
TDA7495SA Package information

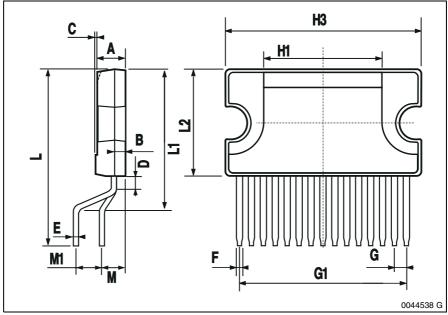
6 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

DIM.		mm			inch	
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			3.2			0.126
В			1.05			0.041
С		0.15			0.006	
D		1.50			0.061	
Е	0.49		0.55	0.019		0.022
F	0.67		0.73	0.026		0.029
G	1.14	1.27	1.4	0.045	0.050	0.055
G1	17.57	17.78	17.91	0.692	0.700	0.705
H1		12			0.480	
H2		18.6			0.732	
Н3	19.85			0.781		
L		17.9			0.704	
L1		14.55			0.572	
L2	10.7	11	11.2	0.421	0.433	0.441
L3		5.5			0.217	
М		2.54			0.100	
M1		2.54			0.100	







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Revision history TDA7495SA

7 Revision history

Table 7.Document revision history

Date	Revision	Description
Sep 2003	1	Initial release
11-Dec 2007	2	Updated package and PCB information

TDA7495SA Revision history

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